MR2535L

Overvoltage Transient Suppressors

Medium Current

Designed for applications requiring a low voltage rectifier with reverse avalanche characteristics for use as reverse power transient suppressors. Developed to suppress transients in the automotive system, these devices operate in the forward mode as standard rectifiers or reverse mode as power avalanche rectifier and will protect electronic equipment from overvoltage conditions.

Features

- Avalanche Voltage 24 to 32 V
- High Power Capability
- Economical
- Increased Capacity by Parallel Operation
- Pb-Free Packages are Available*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 2.5 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Maximum Lead Temperature for Soldering Purposes: 350°C 3/8" from Case for 10 Seconds at 5 lbs. Tension
- Polarity: Indicated by Diode Symbol or Cathode Band

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	V
Repetitive Peak Reverse Surge Current (Time Constant = 10 ms, Duty Cycle \leq 1%, $T_C = 25^{\circ}C$)	I _{RSM}	62	A
Average Rectified Forward Current (Single Phase, Resistive Load, 60 Hz, $T_C = 125^{\circ}C$) (Figure 4)	I _O	6.0	Α
Non-Repetitive Peak Surge Current Surge Supplied at Rated Load Conditions Halfwave, Single Phase	I _{FSM}	600	Α
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



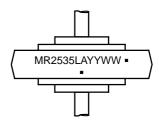
ON Semiconductor®

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MICRODE AXIAL CASE 194 STYLE 1

MARKING DIAGRAM



A = Assembly Location

YY = Year

WW = Work Week

■ = Pb–Free Package (Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MR2535L	Microde Axial	1000 Units/Box
MR2535LG	Microde Axial (Pb-Free)	1000 Units/Box
MR2535LRL	Microde Axial	800/Tape & Reel
MR2535LRLG	Microde Axial (Pb-Free)	800/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

THERMAL CHARACTERISTICS

Characteristic	Lead Length	Symbol	Max	Unit
Thermal Resistance, Junction-to-Lead @ Both Leads to Heatsink, Equal Length	1/4" 3/8" 1/2"	$R_{ hetaJL}$	7.5 10 13	°C/W
Thermal Resistance Junction-to-Case		$R_{ heta JC}$	0.8 (Note 1)	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Instantaneous Forward Voltage (Note 2) (i _F = 100 A, T _C = 25°C)	٧F	-	1.1	V
Reverse Current (V _R = 20 Vdc, T _C = 25°C)	I _R	-	200	nAdc
Breakdown Voltage (Note 2) (I _R = 100 mAdc, T _C = 25°C)	V _(BR)	24	32	V
Breakdown Voltage (Note 2) (I _R = 90 A, T _C = 150°C, PW = 80 μs)	V _(BR)	-	40	V
Breakdown Voltage Temperature Coefficient	V _{(BR)TC}	-	0.096 (Note 1)	%/°C
Forward Voltage Temperature Coefficient @ I _F = 10 mA	V _{FTC}	_	2 (Note 1)	mV/°C

- 1. Typical.
- 2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

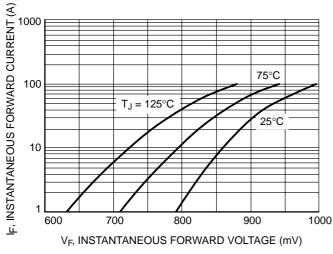
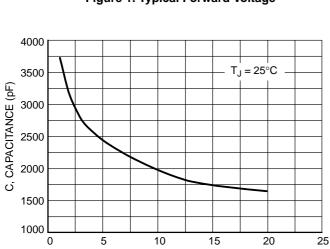


Figure 1. Typical Forward Voltage



V_R, DC BLOCKING VOLTAGE (V) Figure 3. Typical Capacitance

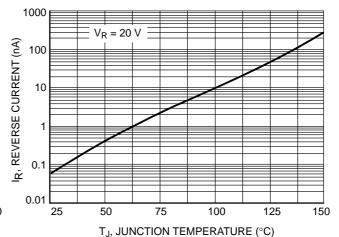


Figure 2. Typical Reverse Current versus Junction Temperature

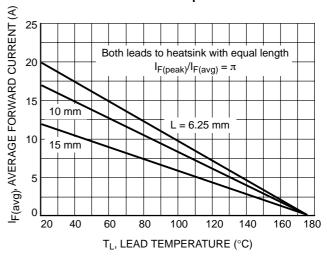


Figure 4. Maximum Current Ratings

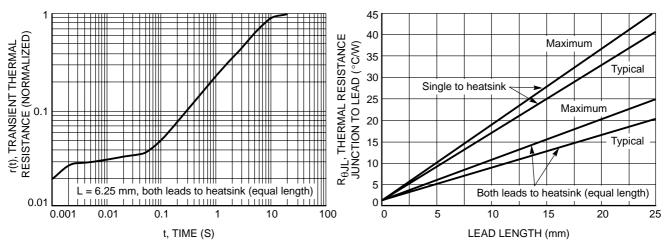


Figure 5. Thermal Response

Figure 6. Steady State Thermal Resistance

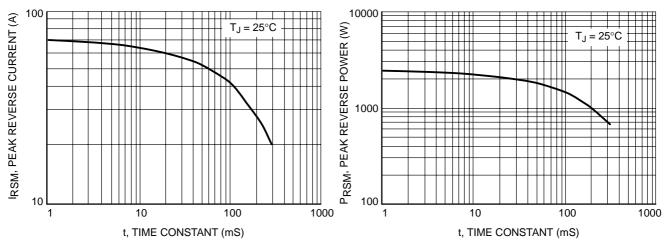


Figure 7. Maximum Peak Reverse Current

Figure 8. Maximum Peak Reverse Power

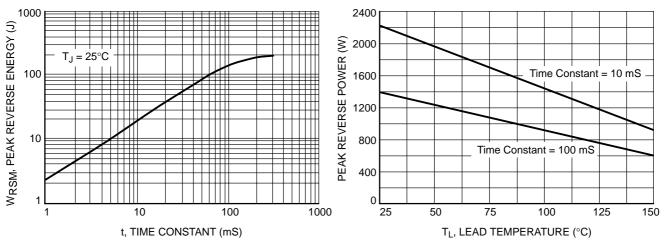


Figure 9. Maximum Reverse Energy

Figure 10. Reverse Power Derating

MR2535L

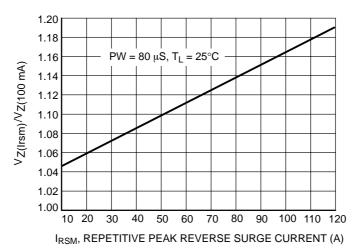


Figure 11. Typical Clamping Factor

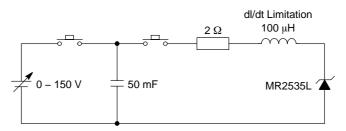


Figure 12. Load Dump Test Circuit

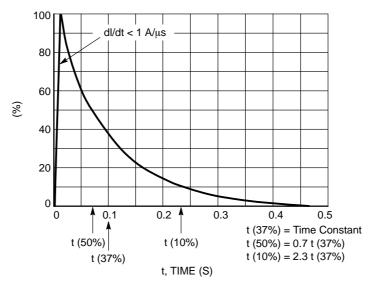
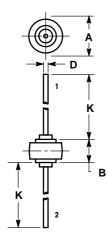


Figure 13. Load Dump Pulse Current

MR2535L

PACKAGE DIMENSIONS

MICRODE AXIAL CASE 194-04 **ISSUE H**



NOTES:

- CATHODE SYMBOL ON PACKAGE.
 194-01 OBSOLETE, 194-04 NEW STANDARD.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.43	8.69	0.332	0.342
В	5.94	6.25	0.234	0.246
D	1.27	1.35	0.050	0.053
K	25.15	25.65	0.990	1.010

STYLE 1: PIN 1. CATHODE 2. ANODE

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